

### **Description**

The AU4521P4-3 is a high power TVS, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive lines. The AU4521P4-3 complies with the IEC 61000-4-2 (ESD) with ±30kV air and ±30kV contact discharge. It is assembled into a 3-pin DFN2020-3 lead-free package. The leads are finished with NiPdAu. Each device will protect one line. The combination of small size, and high surge capability makes them ideal for use in applications such as cellular phones, LCD displays, USB, and multi media card interfaces.

### **Features**

- 6000W peak pulse power (8/20µs)
- Low leakage: nA level
- Operating voltage: 4.5V
- Ultra low clamping voltage
- One power line protects
- Complies with following standards:
  - IEC 61000-4-2 (ESD) immunity test
    Air discharge: ±30kV
    Contact discharge: ±30kV

**Dimensions and Pin Configuration** 

- IEC61000-4-5 (Lightning) 300A (8/20µs)
- RoHS Compliant

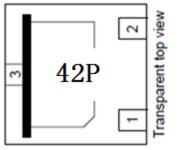
### **Mechanical Characteristics**

- Package: DFN2020-3
- Case Material: "Green" Molding Compound
- Terminal Connections: See Diagram Below
- Marking Information: See Below

#### **Applications**

- Power Management
- Industrial Application
- Power Supply Protection
- Notebooks, desktops, and servers

### Marking Information

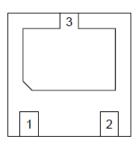


42P:Deavice Marking Code Bar denotes cathode

### **Ordering Information**

Part Number	Packaging	Reel Size	
AU4521P4-3	3000/Tape & Reel	7 inch	





Transparent top view

**Circuit Diagram** 

Pin Schematic



# Absolute Maximum Ratings (T<sub>A</sub>=25°C unless otherwise specified)

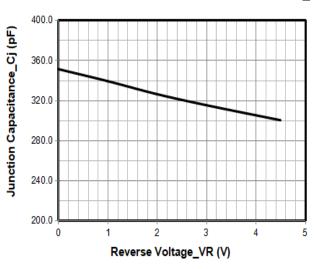
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20µs)	Ppk	6000	W
Peak Pulse Current (8/20µs)	IPP	300	А
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	Vesd	±30 ±30	kV
Operating Temperature Range	TJ	−55 to +125	°C
Storage Temperature Range	Tstg	−55 to +150	°C

# Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise specified)

Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			4.5	V	
Breakdown Voltage	Vbr	4.8			V	IT = 1mA
Reverse Leakage Current	I <sub>R</sub>			1.0	μA	VRWM = 4.5V
Clamping Voltage	Vc			8.5	V	IPP = 50A (8 x 20µs pulse)
Clamping Voltage	Vc			20	V	IPP = 300A (8 x 20µs pulse)
Junction Capacitance	Сл		350		pF	VR = 0V, f = 1MHz

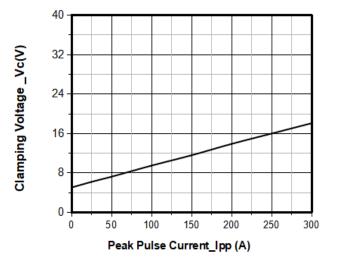


# AU4521P4-3

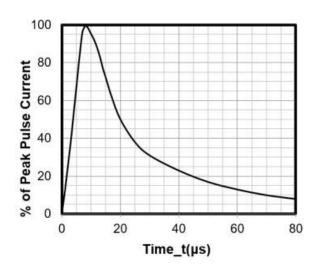


# Typical Performance Characteristics (T<sub>A</sub>=25°C unless otherwise Specified)

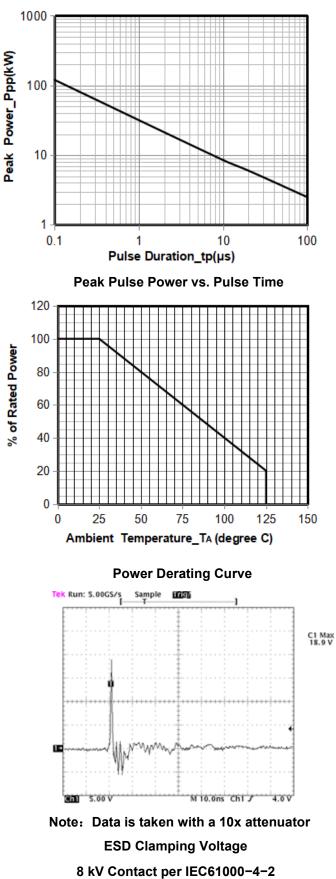
Junction Capacitance vs. Reverse Voltage



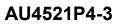
Clamping Voltage vs. Peak Pulse Current



8 X 20µs Pulse Waveform







MAX

0.65

0.05

0.35

2.10

2.10

1.15

1.60

1.40

0.30

0.40

0.45

- -

**MILLIMETERS** 

NOM

0.60

0.02

0.10REF.

- -

- -

- -

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- -

MIN

0.55

0.00

0.25

1.90

1.90

0.95

1.40

1.20

0.20

0.20

0.35

0.13

А

A1

A3

b

D

Е

D2

E2

е

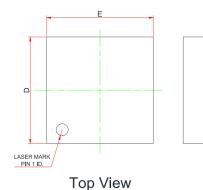
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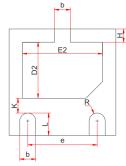
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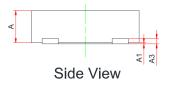
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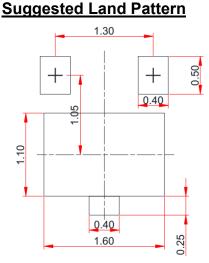
# DFN2020-3 Package Outline Drawing





**Bottom View** 





# **Contact Information**

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